
	<p>SI7958DP-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI7958DP-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2N-CH 40V 7.2A PPAK SO-8</p> <p>Datenblätter:  SI7958DP-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 798898 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7958DP-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2N-CH 40V 7.2A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	798898 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.4W
Verpackung / Gehäuse	PowerPAK® SO-8 Dual
Supplier Device-Gehäuse	PowerPAK® SO-8 Dual
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	7.2A
Rds On (Max) @ Id, Vgs	16.5 mOhm @ 11.3A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	75nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)











SI7958DP-T1-GE3 ist neu im Original, Suche SI7958DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7958DP-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7958DP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7960DP-T1-E3 Vishay / Siliconix MOSFET 2N-CH 60V 6.2A PPAK SO-8</p>	 <p>SI7958DP-T1-E3 VISHAY VISHAY QFN</p>	 <p>SI7958DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 40V 7.2A PPAK SO-8</p>	 <p>SI7958DP SI SI7958DP SI</p>
 <p>SI7956DP-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 150V 2.6A PPAK SO-8</p>	 <p>SI7956DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 150V 2.6A PPAK SO-8</p>	 <p>SI7960DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 60V 6.2A PPAK SO-8</p>	 <p>SI7958DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 40V 7.2A PPAK SO-8</p>

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|---|---|---|--|---|
|  SI7922DN-T1-GE3 |  SI7922DN-T1-GE3 |  SI7923DN-T1-E3 |  SI7923DN-T1-E3 |  SI7923DN-T1-GE3 |
|  SI7923DN-T1-GE3 |  SI7938DP-T1-GE3 |  SI7938DP-T1-GE3 |  SI7940DP |  SI7940DP-T1-E3 |
|  SI7940DP-T1-E3 |  SI7941DP-T1-E3 |  SI7941DP-T1-GE3 |  SI7942DP |  SI7942DP-T1-E3 |
|  SI7942DP-T1-E3 |  SI7942DP-T1-GE3 |  SI7942DP-T1-GE3 |  SI7945DP-T1-E3 |  SI7945DP-T1-E3 |
|  SI7946DP |  SI7946DP-T1-E3 |  SI7946DP-T1-E3 |  SI7948DP |  SI7948DP-T1-E3 |
|  SI7949DP-T1-GE3 |  SI7949DP-T1-GE3 |  SI7956DP-T1-GE3 |  SI7956DP-T1-GE3 |  SI7958DP |
|  SI7958DP-T1-E3 |  SI7958DP-T1-E3 |  SI7958DP-T1-GE3 |  SI7960DP-T1-E3 |  SI7960DP-T1-E3 |
|  SI7960DP-T1-GE3 |  SI7960DP-T1-GE3 |  SI7964DP |  SI7964DP-T1-GE3 |  SI7964DP-T1-GE3 |
|  SI7970DP |  SI7970DP-T1-E3 |  SI7980DP-T1-E3 |  SI7980DP-T1-E3 |  SI7980DP-T1-GE3 |
|  SI7980DP-T1-GE3 |  SI7997DP-T1-GE3 |  SI7997DP-T1-GE3 |  SI7998DP-T1-GE3 |  SI7998DP-T1-GE3 |

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